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APPLICATION NO.	F	ILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/941,533	08/29/2001		Ammar Derraa	MTI-31533	4578
31870	7590	07/11/2005		EXAMINER	
WHYTE H	IRSCHB	OECK DUDEK S.	FOURSON III, GEORGE R		
555 EAST V	VELLS ST	ΓREET			
SUITE 1900				ART UNIT	PAPER NUMBER
MILWAUKEE, WI 53202			2823		
				DATE MAIL ED: 07/11/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)					
	09/941,533	DERRAA, AMMAR					
Office Action Summary	Examiner	Art Unit					
	George Fourson	2823					
The MAILING DATE of this communication app Period for Reply		<u> </u>					
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a repl - If NO period for reply is specified above, the maximum statutory period of - Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be tin y within the statutory minimum of thirty (30) day will apply and will expire SIX (6) MONTHS from e, cause the application to become ABANDONE	nely filed /s will be considered timely. Ithe mailing date of this communication. ED (35 U.S.C. § 133).					
Status							
1) Responsive to communication(s) filed on 03 M	lay 2005.						
2a) This action is FINAL . 2b) ⊠ This	action is non-final.						
•	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims							
4) ⊠ Claim(s) 1-73 and 101-129 is/are pending in the 4a) Of the above claim(s) is/are withdraw 5) □ Claim(s) is/are allowed. 6) ⊠ Claim(s) 1-73 and 101-129 is/are rejected. 7) □ Claim(s) is/are objected to. 8) □ Claim(s) are subject to restriction and/or	wn from consideration.						
Application Papers							
9) The specification is objected to by the Examiner.							
0) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner.							
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).							
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d). 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.							
Priority under 35 U.S.C. § 119							
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority document application from the International Bureau * See the attached detailed Office action for a list	s have been received. s have been received in Applicati rity documents have been receive u (PCT Rule 17.2(a)).	ion No ed in this National Stage					
Attachment(s)							
1) Notice of References Cited (PTO-892)	4) Interview Summary						
 Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date 	Paper No(s)/Mail Di 5) Notice of Informal F 6) Other:	ate Patent Application (PTO-152)					

A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 5/3/05 has been entered.

Claims 1,2,3-9,11,12,13,14,16,17,18,19,21,22,23,24,26,27,28,30,31,33,34,35,37,38,40-45,49,68,71,101-105,112,114,116,120 and 121 are rejected under 35 U.S.C. 103(a) as being unpatentable over Wang et al in view of Hu et al.

The rejection is maintained as stated in the paper mailed 2/3/05.

Wang discloses treatment of a contact having a thickness up to 1000 angstroms [0024][0048].

Hu exemplifies treatment of a 1400 angstrom film (fig.3 and col.5, line 49) at "about 680°C" (col.5, line 31) which includes some variation from 680°C in view of use of the term "about". The recited temperature of 700°C would not have been expected to materially alter the treatment step because the difference in temperature between "about 680°C" and 700°C would not have been expected to be large enough to impart substantial differences in the effects of the step. Furthermore, it appears that 680°C treatment is exemplified to simplify the process by using the same temperature as the deposition temperature in the "Example" ("maintained", col. 6, line 64). Note that the deposition temperature is disclosed to be 550-720°C (col.6, lines 23-24). Therefor, it appears that there is overlap between the disclosed deposition temperature range, and therefor the temperature range of the heat treatment, and that disclosed by the reference. If overlap is not disclosed one of ordinary skill in the art would have been led to

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the recited temperature when using deposition temperatures over 700°C to simplify the process of forming the contact.

Claim 115 is rejected under 35 U.S.C. 103(a) as being unpatentable over Wang et al in combination with Hu et al as applied to claims 1,2,3-9,11,12,13,14,16,17,18,19,21,22,23,24,26,27, 28,30,31,33,34,35,37,38,40-45,49,68,71,101-105,112,114,116,120 and 121 above, and further in view of Leem or Japan 5-267220.

The rejection is maintained as stated in the paper mailed 2/3/05 and as stated above. In addition to suggesting incorporation of B in the film of Wang et al It would have been obvious to one of ordinary skill in the art to form a 100 angstrom Ti-B-N barrier layer as part of the contact structure of Wang et al in view of the teachings of Leem and Japan '220 that Ti-B-N is a conductive material useful in a contact structure.

Applicant argues that there is no disclosure in Leem or Japan 5-267220 related to use of boron-doped titanium nitride to fill the entire opening. However, neither of the references is alleged to contain such a teaching. Leem or Japan '220 are relied on as providing motivation to incorporate boron in the TiN material of Wang et al in view of Hu et al in at least one of the deposition/treatment steps with a reasonable expectation that the resulting Ti-B-N material would have the necessary properties to function as a layer in the contact of Wang et al. Leem expresses a preference for Ti-B-N films less than 100 angstroms thick (col.2, line 36) but characterization of embodiments as non-preferred does not constitute a teaching away. In view of the material being used in a contact structure It would have been obvious to one of ordinary skill

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in the art to employ the material in the contact structure of Wang et al or, alternatively, to modify the contact material of Wang et al to include incorporation of B.

Claims 10,15,20,25,29,32,39,50,51-59,61,62,63,67,66,69,70,73,106,107,108,109,72,110,111, 113,117,118,119,122,123,128 and 129 are rejected under 35 U.S.C. 103(a) as being unpatentable over Wang et al in combination with Hu et al as applied to claims 1,2,3-9,11,12,13,14,16,17, 18,19,21,22, 23,24,26,27, 28, 30,31,34,35,37,38,40-45,49,68,71,101-105,112,114,116,120 and 121 above, and further in view of Leem or Japan '220.

The rejection is maintained as stated in the paper mailed 2/3/05 and as stated above.

Claims 36,46,47,48,64 and 65 are rejected under 35 U.S.C. 103(a) as being unpatentable over Wang et al in view of Hu et al as applied to claims 1,2,3-9,11,12,13,14,16,17,18,19,21,22,23,24,26,27, 28,30,31,33,34,35,37,38,40-45,49,68,71,101-105,112,114,116,120 and 121 above, and further in view of Doan et al.

The rejection is maintained as stated in the paper mailed 2/3/05 and as stated above.

Claims 60,124,125,126 and 127 are rejected under 35 U.S.C. 103(a) as being unpatentable over Wang et al as applied to claims 1,2,3-9,11,12,13,14,16,17,18,19,21,22,23,24,26,27, 28,30,31,33,34, 35,37,38,40-45,49,68,71,101-105,112,114,116,120 and 121 above, and further in view of AAPA.

The rejection is maintained as stated in the paper mailed 2/3/05 and as stated above.

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The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Yokoyama 4897709 cited by applicant discloses formation of TiN at 200-900°C (col.4, lines 54+). Eichman 5279857, cited by applicant, teaches thermal anneal at 600-700°C (col.3). Both of Japan 10-172924 and 10-223563, cited by applicant, disclose reducing CI content in a TiN film.

Any inquiry of a general nature or relating to the status of this application should be directed to the Group Receptionist whose telephone number is (571) 272-2800. See MPEP 203.08.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to examiner George Fourson whose telephone number is (571)272-1860. The examiner can normally be reached on Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Olik Chaudhuri, can be reached on (571)272-1855. The fax number for this group is (571)273-0224 and the customer service number for group 2800 is 571-272-2815. Updates can be found at http://www.uspto.gov/web/info/2800.htm.

George Flourson
Primary Examiner
Art Unit 2823

GFourson July 5, 2005